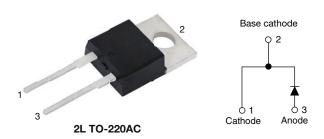


Hyperfast Rectifier, 30 A FRED Pt® G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS								
I _{F(AV)}	30 A							
V_{R}	1200 V							
V _F at I _F at 125 °C	2.1 V							
t _{rr}	26 ns							
T _J max.	175 °C							
Package	2L TO-220AC							
Circuit configuration	Single							

FEATURES

Hyperfast and optimized Q_{rr}



 Best in class forward voltage drop and switching RoHS losses trade off

HALOGEN **FREE**

Optimized for high speed operation

• 175 °C maximum operating junction temperature

Polyimide passivation

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant.

Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

Polarity: as per marking device details

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Repetitive peak reverse voltage	V_{RRM}		1200	V					
Average rectified forward current	I _{F(AV)}	T _C = 83 °C, D = 0.50	30						
Non-repetitive peak surge current	I _{FSM}	T_C = 83 °C, t_p = 10 ms, sine wave	190	Α					
Repetitive peak forward current	I _{FRM}	T _C = 45 °C, D = 0.50, f = 20 kHz	60						
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Breakdown voltage, blocking voltage	V_{BR} , V_{R}	I _R = 100 μA	1200	-	-	.,			
Farmend valtage	W	I _F = 30 A	-	2.6	3.3	V			
Forward voltage	V _F	I _F = 30 A, T _J = 125 °C	-	2.1	-				
Developed legisland assument	I _R	$V_R = V_R$ rated	-	-	50				
Reverse leakage current		$T_J = 125$ °C, $V_R = V_R$ rated		500	μΑ				
Junction capacitance	C _T	V _R = 200 V	-	17	-	pF			
Series inductance	L _S	Measured to lead 5 mm from package body	ı	8	-	nH			



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			47				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	100	-	ns			
		T _J = 125 °C		-	150	-	1			
Dook recovery ourrent	1	T _J = 25 °C	I _F = 20 A dI _F /dt = 600 A/μs V _B = 400 V	-	12	-	Α			
Peak recovery current	I _{RRM}	T _J = 125 °C		-	22	-				
Doverso vecessors charge	0	T _J = 25 °C		-	530	-	nC			
Reverse recovery charge	Q_{rr}	T _J = 125 °C		-	1650	-				
Poverse receivery time	t _{rr}	T _J = 25 °C		-	80	-	ns A			
Reverse recovery time		T _J = 125 °C		-	120	-				
Dools recovery oursent	I _{RRM}	T _J = 25 °C	I _F = 30 A	-	22	-				
Peak recovery current		T _J = 125 °C	dl _F /dt = 1000 A/μs V _B = 800 V	-	37	-				
Poverse receivent charge	0	T _J = 25 °C		-	900	-	nC			
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	2400	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.1	°C/W				
Weight			-	2.0	-	g				
vveignt			-	0.07	-	OZ.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55		175	°C				
Marking device		Case style: 2L TO-220AC	E5TX3012							

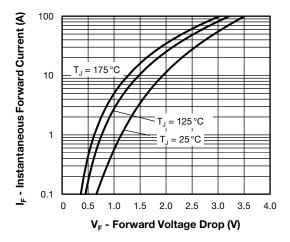


Fig. 1 - Typical Forward Voltage Drop Characteristics

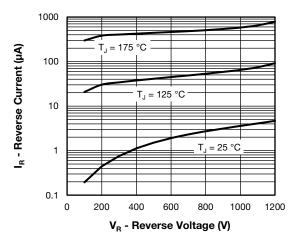


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



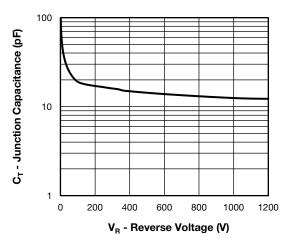


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

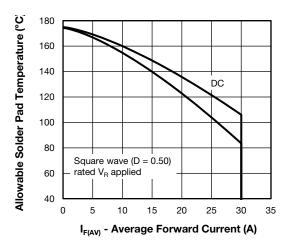


Fig. 4 - Maximum Allowable Case Temperature vs.
Average Forward Current

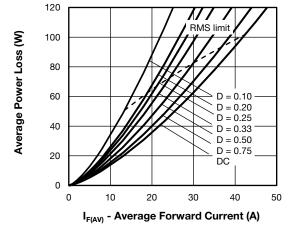


Fig. 5 - Typical Recovery Current vs. dl_F/dt

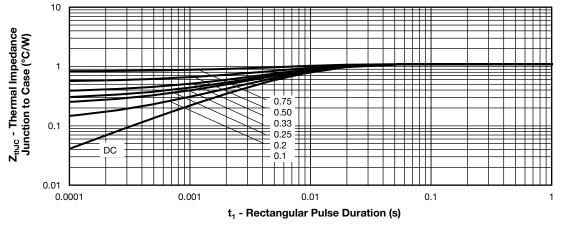


Fig. 6 - Thermal Impedance Z_{thJC} Characteristics



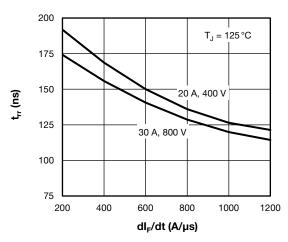


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

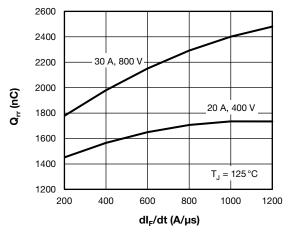


Fig. 8 - Typical Stored Charge vs. dl_F/dt

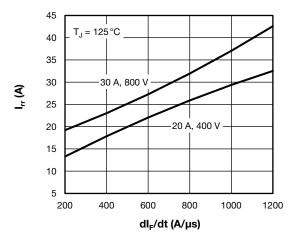


Fig. 9 - Typical Recovery Current vs. dl_F/dt

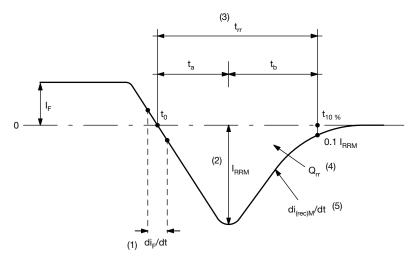


Fig. 10 - Reverse Recovery Waveform and Definitions

Notes

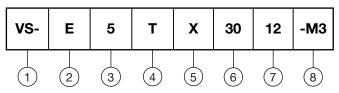
- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}$ Q_{rr} area under curve defined by t_0 and t_{10} %

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t)dt$$

(5) di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- **2** E = single diode
- 3 5 = FRED generation 5
- 4 Package: T = 2L TO-220AC
- 5 X = hyperfast recovery
- 6 Current rating (30 = 30 A)
- 7 Voltage rating (12 = 1200 V)
- 8 Environmental digit:

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

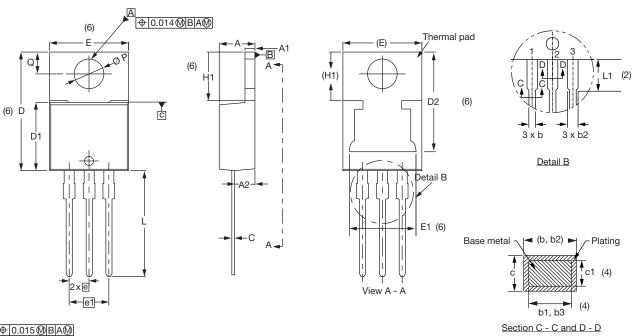
ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-E5TX3012-M3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96154
Part marking information	www.vishay.com/doc?95391

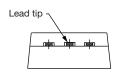


3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7	
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6	
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6	
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105		
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208		
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6	
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552		
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2	
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154		
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118		
D1	8.38	9.02	0.330	0.355		1		•			•		

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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Vishay

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